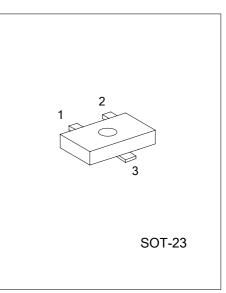
### UTC BCX70

## NPN EPITAXIAL SILICON TRANSISTOR

#### GENERAL PURPOSE TRANSISTOR

#### MARKING





1: Emitter 2: Base 3: Collector \*Pb-free plating product number: BCX70L

#### ABSOLUTE MAXIMUM RATINGS

(Ta =  $25^{\circ}$ C unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT	
Collector-Base Voltage	V <sub>CBO</sub>	45	V	
Collector-Emitter Voltage	V <sub>CEO</sub>	45	V	
Emitter-Base Voltage	V <sub>EBO</sub>	5	V	
Collector Current	Ic	200	mA	
Collector Power Dissipation	Pc	350	mW	
Storage Temperature	T <sub>STG</sub>	-40 ~ +150	°C	

#### **ELECTRICAL CHARACTERISTICS**

(Ta =  $25^{\circ}$ C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =2.0mA, I <sub>B</sub> =0	45			V
Emitter-Base Breakdown Voltage	$BV_{EBO}$	I <sub>E</sub> =1.0μF, I <sub>C</sub> =0	5			V
Collector Cut-off Current	I <sub>CES</sub>	V <sub>CE</sub> =32V, V <sub>BE</sub> =0			20	nA
Emitter Cut-off Current	I <sub>EBO</sub>	$V_{EB}=4V, I_{C}=0$			20	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10µA	100			
		V <sub>CE</sub> =5V, I <sub>C</sub> =2.0mA	380		630	
		V <sub>CE</sub> =1V, I <sub>C</sub> =50mA	100			
Collector-Emitter Saturation Voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0.25mA			0.35	V
		I <sub>C</sub> =50mA, I <sub>B</sub> =1.25mA			0.55	V
Base-Emitter Saturation Voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0.25mA	0.6		0.85	V
		I <sub>C</sub> =50mA, I <sub>B</sub> =1.25mA	0.7		1.05	V
Base-Emitter On Voltage	V <sub>BE (on)</sub>	I <sub>C</sub> =2.0mA, V <sub>CE</sub> =5V	0.55		0.75	V
Current Gain Bandwidth Product	f <sub>⊤</sub>	I <sub>C</sub> =10mA, V <sub>CE</sub> =5V, f=100MHz	125			MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz			4.5	P⁺
Noise Figure	NF	V <sub>CE</sub> =5V, I <sub>C</sub> =0.2mA, R <sub>S</sub> =2KΩ f=1KHz			6	dB
Turn On Time	t <sub>on</sub>	I <sub>C</sub> =10mA, I <sub>B1</sub> =1.0mA			150	ns
Turn Off Time	t <sub>OFF</sub>	$V_{BB}$ =3.6V, $I_{B2}$ =1.0mA, $R_1$ = $R_2$ =5K $\Omega$ $R_L$ =990 $\Omega$			800	ns

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